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# MAGNETRON SPUTTERED YHO THIN FILM OXYDATION DYNAMICS AND OPTICAL PROPERTIES

M.ZUBKINS, I. AULIKA, E. STRODS, V. VIBORNIJS, L. BIKSE, A. SARAKOVSKIS, J. PURANS

## INSTITUTE OF SOLID STATE PHYSICS, UNIVERSITY OF LATVIA

THIN FILMS LABORATORY



LATVIJAS UNIVERSITĀTES CIETVIELU FIZIKAS INSTITŪTS

INSTITUTE OF SOLID STATE PHYSICS University of Latvia







Latvian Council of Science

# OUTLINE



- Motivation
- Introduction in rare-earth oxyhydrides
- Experimental details
- Results:
  - In-situ transmittance measurements
  - X-ray diffraction
  - Electron microscope images
  - Spectroscopic ellipsometry
  - X-ray photoelectron spectroscopy (depth profiling)
- Conclusions



# MOTIVATION



nsulating gap

Inner pane (with low-e coating)

• Yttrium and other rare-earth (RE) metal oxy-hydrides (YHO, REHO) are a new class of inorganic **mixed-anion materials** [1]

- They exhibit a **photochromic effect and a light-induced resistivity change** at room temperature and ambient pressure [2]
- Photochromic YHO thin films can be prepared by the simply exposing reactively  $(Ar+H_2)$  sputtered metallic  $B-YH_2$  films to air [3]. However, it has not been directly measured when the oxidation mostly occurs after or during (due to residual oxygen) the deposition of YH<sub>2</sub> films?
- The aim of this presentation to show the oxidation dynamics of yttrium hydride films during and after deposition process, as well as optical properties.
- Latvian Council of Science FLPP project: Thin films of rareearth oxy-hydrides for photochromic applications
- [1] Nature communications 9.1 (2018) 1-15
- [2] Applied Physics Letters 111 (2017) 103903.
- [3] Sol. Energy Mater. Sol. Cells 177 (2018) 106



Double-paned insulated glass unit (IGU)







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# YTTRIUM OXYHYDRIDE



Cryst. Growth Des. 2019, 19, 2574–2582

Physical Review Materials 4.2 (2020): 025201.





YH<sub>2</sub> fcc Fm-3m





# **PHOTOCHROMIC EFFECT**

## **UV-Blue** light irradiation



Physical Review Materials, 4(2), 025201 (2020)



Appl. Phys. Lett. 111, 103903 (2017)



# EXPERIMENTAL DETAILS - YHO DEPOSITION



## Vacuum coater Sidrabe G500M

### Sputtering conditions:

- rectangular magnetron: balanced;
- o target:
  - Y (99.95 purity);
  - dimensions 150 mm × 75 mm × 2 mm thick.
- working pressure 3 20 mTorr (changed by a throttle valve):
  - Ar flow 30 sccm;
  - H<sub>2</sub> flow 16 sccm.
- constant average power regime (200 W);
- pulsed-DC power supply P-DC-EP05 EnerPulse 5 kW:
  - •frequency 80 kHz;
  - ■Off time 2.5 µs;
- spectrometer: CMOS detector, StarLine AvaSpec-ULS2048CL-EVO

## YHO deposition:

- $\circ$  soda-lime glass and Ti substrates;
- substrate temperature: RT (without intentional heating);
- deposition time: 20 min;
- $\circ$  distance from target to substrate: ~10 cm (facing the target axis);







# **DEPOSITED YHO SAMPLES**

Sample	Sputtering	Voltage (V)	Thickness
No.	pressure		(nm)
	(mTorr)		
1	3.0	302	330
2	6.0	299	209
3	6.5	299	305
4	7.0	299	357
5	7.5	297	378
6	8.0	298	428
7	9.0	296	442
8	10.0	299	419
9	12.0	296	398
10	20.0	290	462







# IN-SITU TRANSMITTANCE MEASUREMENT





# **IN-SITU TRANSMITTANCE**



Transmittance spectra of the deposited samples immediately after the deposition.





# **IN-SITU TRANSMITTANCE**

# Transmittance spectra of the deposited samples <u>immediately after the deposition</u>.



Transmittance spectra of the deposited samples after 30 min in  $O_2$  ( $\approx$  3 Torr).





# TIME CONSTANT









# **XRD OF YHO**







The surface morphology of the films is less dense at higher sputtering pressures.





# **CROSS-SECTION IMAGES OF YHO FILMS**







HV det mode HFW PW mag 20.00 kV STEM 3+ HAADF 1.73 μm 1.12 nm 120 000 ×



# **OPTICAL CONSTANTS**



The refractive index n (a, c) and extinction coefficient k (b, d) as functions of photon energy and sputtering pressure. Refractive index n and extinction coefficient k at 400 nm wavelength as functions of sputtering pressure.



Pressure, mTorr



# **OPTICAL BAND GAP**



Tauc band gap  $E_g$  (fitting parameter of TLO) as a function of the sputtering pressure.







# **OPTICAL GRADIENT**

Optical depth profile (at 1.669 eV or 742.8 nm) of thin films sputtered at different pressures.





# **XPS - DEPTH PROFILING**





XPS Survey 1 Scan, 27.2 s, 200µm, CAE 150.0, 1.00 eV







Fi2p3 Combin

01s Combine

Atomic % Profile

1 Scan, 0.050 s, 200µm, CAE 20.0, CAE 20.0

# 7.0 mTorr

YHO film

110

100-

90·

80

70-

50

Atomic % (%) 60-

# **DEPTH PROFILING**

YHO films on the Ti substrates

Ti substrate

8.0 mTorr

YHO film

100

90

80

60

50

Atomic % Profile

1 Scan, 0.050 s, 200µm, CAE 20.0, CAE 20.0

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Ti substrate



Ti2p3 Combined

O1s Combined

Y3d5 Combined



- The oxidation of  $YH_{2-x}$  films during and after deposition occur more rapidly when the higher sputtering pressure is used.
- The most of the oxidation happens when oxygen (or air) is introduced into a vacuum chamber intentionally.
- The lattice of YHO films expands with the deposition pressure due the higher oxygen concentration which is promoted by the less dense structure.
- There is the transition from metallic to semiconducting/insulating YHO films when the deposition pressure is increased (at 7.0 mTorr in our case).
- The transparent films in the visible light range exhibit an optical gradient throughout the thickness of the films due to the nonhomogeneous composition.





# Thanks for Your attention !!!



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